



BCV49

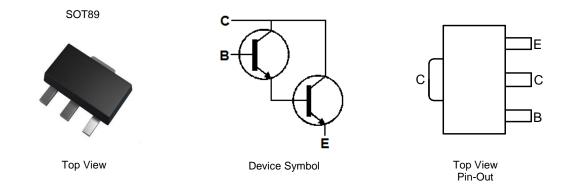
#### 60V NPN DARLINGTON TRANSISTOR IN SOT89

#### Features

- BV<sub>CEO</sub> > 60V
- Darlington Transistor h<sub>FE</sub> > 10k @ 100mA for High Gain
- I<sub>C</sub> = 500mA High Continuous Collector Current
- Complementary Darlington PNP Type: FCX705
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight 0.052 grams (Approximate)



### Ordering Information (Note 4)

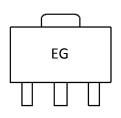
Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
BCV49TA	AEC-Q101	EG	7	8	3,000
Notes: 1 No purposely added lead. Fully FU Directive 2002/95/FC (RoHS), 2011/65/FU (RoHS 2) & 2015/863/FU (RoHS 3) compliant					

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**



EG = Product Type Marking Code



## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	10	V
Continuous Collector Current	lc	500	mA
Peak Pulse Current	I <sub>CM</sub>	800	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Rewar Dissinguing	(Note 5)		1.1	W	
Power Dissipation	(Note 6)	PD	1.5	v	
Thermal Desistance, lunction to Ambient	(Note 5)	P	113	90AM	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	83	°C/W	
Thermal Resistance, Junction to Leads (Note 7)		R <sub>θJL</sub>	9.9	°C/W	
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C		

## ESD Ratings (Note 8)

Notes:

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

 For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.

7. Thermal resistance from junction to solder-point (on the exposed collector pad).

8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



120

100

80

60

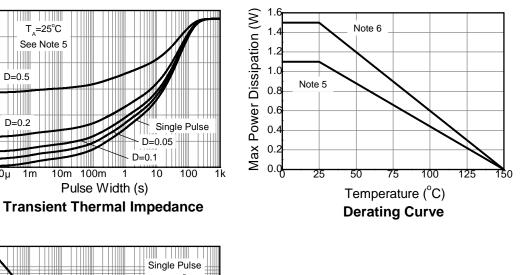
40 D=0.2

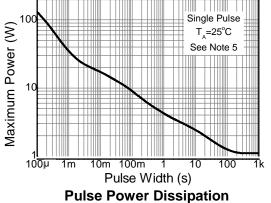
20

100µ

D=0.5

Thermal Resistance (<sup>°</sup>C/W)







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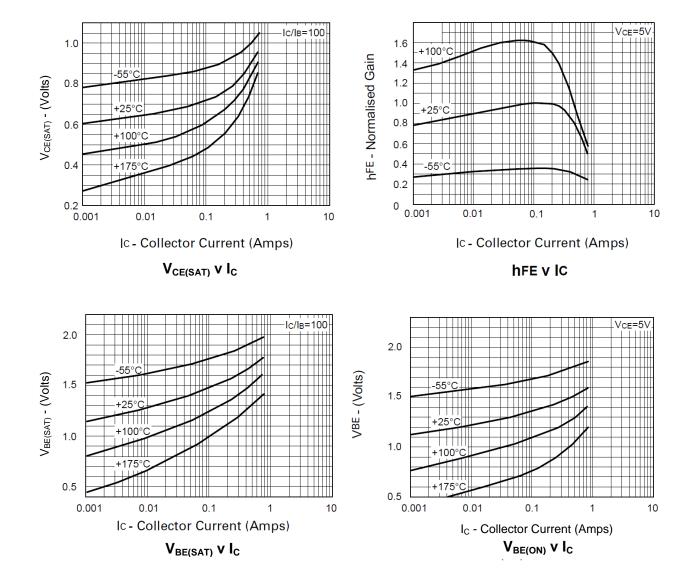
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	80	_	_	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	60	_	_	V	I <sub>CEO</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	10	_	_	V	I <sub>EBO</sub> = 10μA
Collector Cut-Off Current	I <sub>CBO</sub>	_	<1	100	nA	$V_{CB} = 60V$
		—	_	10	μA	$V_{CB} = 60V, T_A = +150^{\circ}C$
Emitter-Base Cut-Off Current	I <sub>EBO</sub>	—	<1	100	nA	$V_{EB} = 4V$
ON CHARACTERISTICS (Note 9)						
Static Forward Current Transfer Ratio	h <sub>FE</sub>	2,000 4,000 10,000 2,000	_	_	_	$\begin{split} I_{C} &= 100 \mu A, \ V_{CE} = 1 V \\ I_{C} &= 10 m A, \ V_{CE} = 5 V \\ I_{C} &= 100 m A, \ V_{CE} = 5 V \\ I_{C} &= 500 m A, \ V_{CE} = 5 V \end{split}$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	—	_	1.0	V	$I_{\rm C} = 100 {\rm mA}, I_{\rm B} = 0.1 {\rm mA}$
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	—	_	1.5	V	$I_{\rm C} = 100 {\rm mA}, I_{\rm B} = 0.1 {\rm mA}$
SMALL SIGNAL CHARACTERISTICS (Note 9)						
Transition Frequency	f <sub>T</sub>	_	170	_	MHz	$I_C = 50 \text{mA}, V_{CE} = 5 \text{V},$ f = 20MHz
Output Capacitance	C <sub>OBO</sub>	_	3.5	_	pF	V <sub>CB</sub> = 10V, f = 1MHz

Note 9: Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



# **Typical Electrical Characteristics**

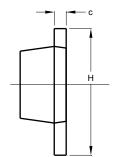




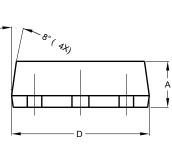
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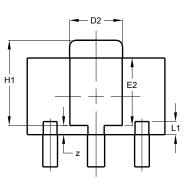
## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT89

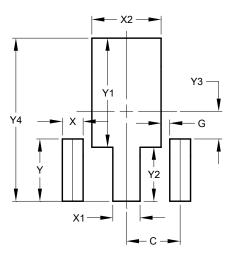




SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	1	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
z	0.20	0.40	0.30		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Value Dimensions (in mm) 1.500 С G 0.244 Χ 0.580 X1 0.760 X2 1.933 Υ 1.730 Y1 3.030 Y2 1.500 Y3 0.770 Y4 4.530

SOT89



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